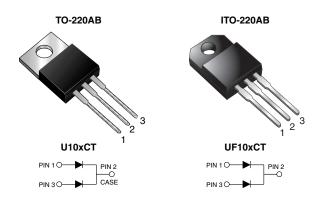


## U(F,B)10BCT thru U(F,B)10DCT

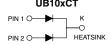
Vishay General Semiconductor

## **Dual Common-Cathode Ultrafast Rectifier**









PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	5 A x 2					
$V_{RRM}$	100 V, 150 V, 200 V					
I <sub>FSM</sub>	55 A					
t <sub>rr</sub>	25 ns					
$V_{F}$	0.89 V					
T <sub>J</sub> max.	150 °C					

#### **FEATURES**

Oxide planar chip junction



Ultrafast recovery time

Soft recovery characteristics



· Low switching losses, high efficiency

ROHS

· High forward surge capability

· High frequency operation

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB, IT-220AB)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB and TO-263AB Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test **Polarity:** As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER		U(F,B)10BCT U(F,B)10CCT		U(F,B)10DCT	UNIT		
Maximum repetitive peak reverse voltage	$V_{RRM}$	100	150	200	٧		
Max. average forward rectified current (Fig. 1) total device per diode	I <sub>F(AV)</sub>	10 5			Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	55			А		
Electrostatic discharge capacitor voltage, human body model: C = 150 pF, R = 1.5 k $\Omega$ (contact mode)	V <sub>C</sub>	8			kV		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min per diode	V <sub>AC</sub>	1500			V		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150			°C		

Document Number: 88967 Revision: 13-May-08

# U(F,B)10BCT thru U(F,B)10DCT

## Vishay General Semiconductor



<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage per diode <sup>(1)</sup>	I <sub>F</sub> = 3.0 A I <sub>F</sub> = 5.0 A	T <sub>J</sub> = 25 °C	· V <sub>F</sub>	0.97 1.05	- 1.10	V	
	I <sub>F</sub> = 3.0 A I <sub>F</sub> = 5.0 A	T <sub>J</sub> = 150 °C		0.79 0.89	- 0.95		
Maximum reverse current per diode (2)	rated V <sub>R</sub>	$T_J = 25$ °C $T_J = 100$ °C	I <sub>R</sub>	0.5 100	5.0 200	μΑ	
Maximum various recovers time nov diade	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>rr</sub> = 0.25 A		t <sub>rr</sub>	13	20	ns	
Maximum reverse recovery time per diode	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s},$ $V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$			19.7	25		
Maximum stored charge per diode	$I_F = 2 \text{ A}, \text{ dI/dt} = 20 \text{ A/}\mu\text{s},$ $V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		Q <sub>rr</sub>	3	9	nC	

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	U10xCT	UF10xCT	UB10xCT	UNIT
Typical thermal resistance per diode	$egin{aligned} R_{ hetaJA}\ R_{ hetaJC} \end{aligned}$	25 5.3	25 7.5	25 5.3	°C/W

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	U10DCT-E3/4W	1.87	4W	50/tube	Tube	
ITO-220AB	UF10DCT-E3/4W	1.77	4W	50/tube	Tube	
TO-263AB	UB10DCT-E3/4W	1.31	4W	50/tube	Tube	
TO-263AB	UB10DCT-E3/8W	1.31	8W	800/reel	Tape and reel	



## Vishay General Semiconductor

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

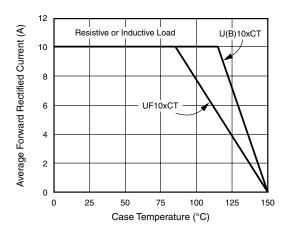


Figure 1. Maximum Forward Current Derating Curve

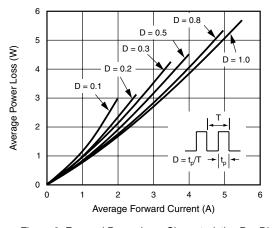


Figure 2. Forward Power Loss Characteristics Per Diode

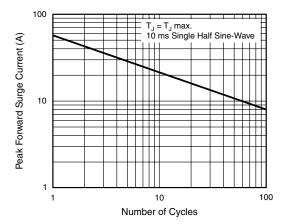


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

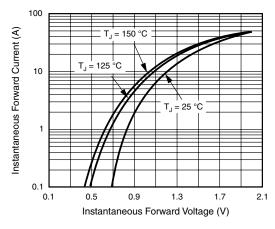


Figure 4. Typical Instantaneous Forward Characteristics Per Diode

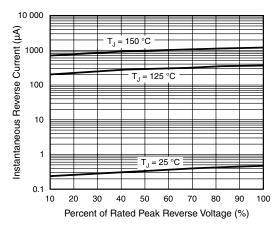


Figure 5. Typical Reverse Characteristics Per Diode

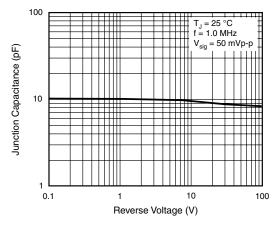


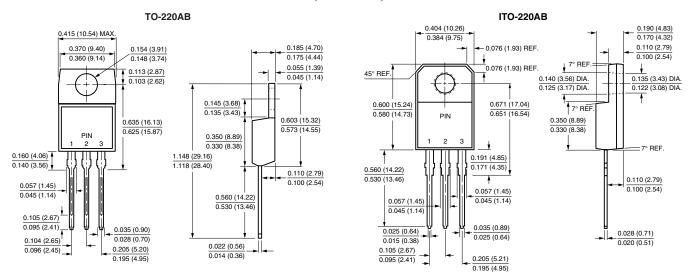
Figure 6. Typical Junction Capacitance Per Diode

# U(F,B)10BCT thru U(F,B)10DCT

## Vishay General Semiconductor

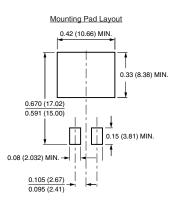


#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



#### TO-263AB 0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.055 (1.40) 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.360 (9.14) 0.320 (8.13) 0.624 (15.85) -0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79)

0.195 (4.95)



## **Legal Disclaimer Notice**



Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 www.vishay.com
Revision: 11-Mar-11 1